

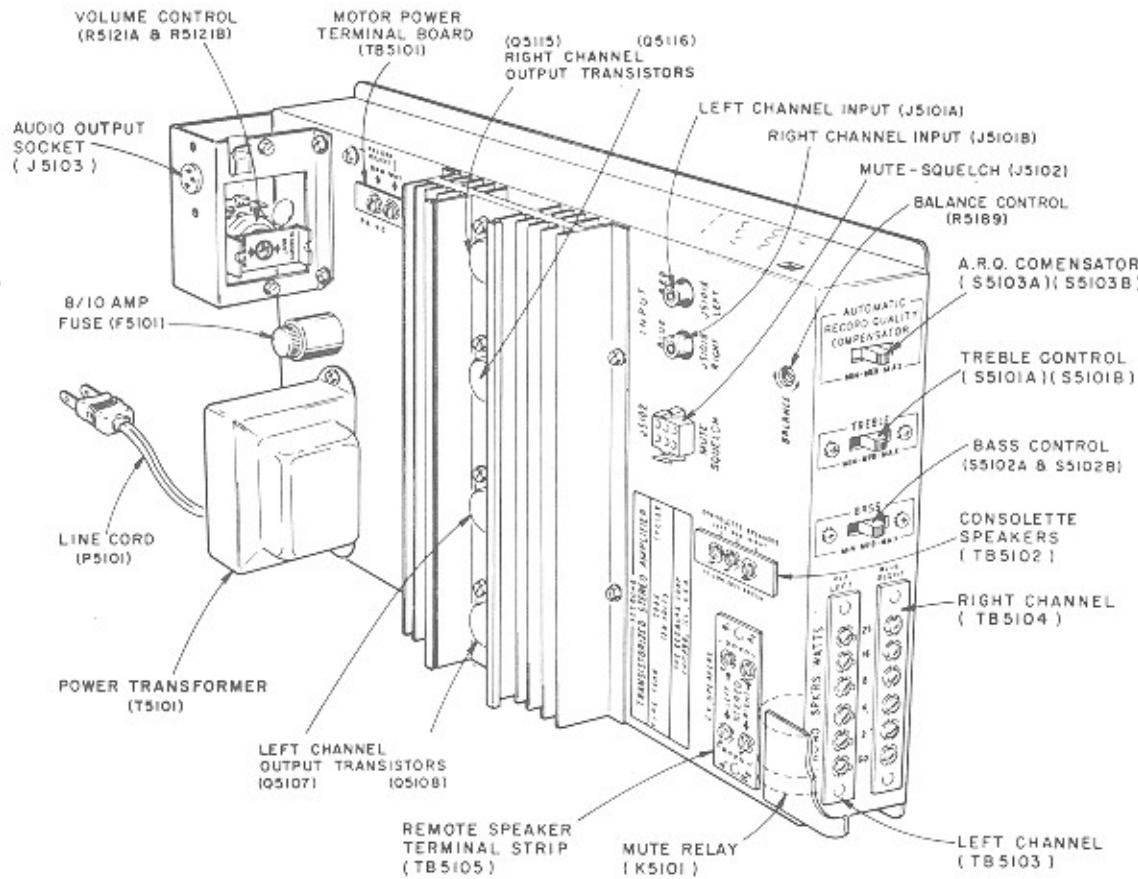
TRANSISTORIZED STEREO AMPLIFIER, Type TSA4

This is a fully transistorized dual channel stereo, low distortion, wide frequency range, constant voltage type amplifier. It is part of the Seeburg Stereophonic Sound System that includes the Seeburg stereo pickup, one or more pairs of Seeburg twin stereo speakers, as well as a speaker coupling network and speakers mounted in the cabinet.

The two output signals of the low impedance magnetic pickup of the Select-O-Matic mechanism are connected to the amplifier through the input sockets and have a nominal signal level for each channel of five millivolts. Both signals are independently amplified, one in the left channel, one in the right channel. Each channel is complete with the tone controls and the volume control mechanically linked to provide equal and simultaneous positioning.

The output transformers of each channel have low and high impedance terminals. Each low impedance winding drives the phonograph speakers whose connections are made through the speaker terminal boards, TB5103 and TB5104. Stereo Consolette 32-ohm speakers are connected to the low impedance winding through terminal board TB5102.

The high impedance secondaries of the output transformers are 70-volt C.V. outputs that terminate at A and B terminals of the remote speaker terminal strip, TB5105. These outputs drive the side channels of one or more external stereo speakers that have, in their enclosure, a highpass network. External speakers for monaural operation may be connected to the remote speaker terminal strip, terminals A1 and B2 or to A2 and B1.



NOTE: CONSOLETTE SPEAKERS, 32 OHMS; ALL OTHERS 5 OHMS; REFLECTED IMPEDANCE OF CABINET SPEAKERS AND COUPLING NETWORK, 5 OHMS EACH CHANNEL.

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The total output power for each channel is divided between the Stereo Consolette speakers, the cabinet speakers in the phonograph and the external stereo speakers. The output power to the speakers in the phonograph and the external stereo speakers can be varied by positioning the phonograph speaker terminals and the loading taps on the external speakers. The phonograph speaker terminals are calibrated in watts with reference to the power delivered at full output by each output transformer to the 5-ohm phonograph speaker load. The output to the Consolette speakers is connected to the 2 watt transformer tap; however, since the speaker impedance is 32 ohms, the effective power is one watt per speaker. The total load of the cabinet speakers in the phonograph as indicated on the speaker terminals and the load of remote speakers must not be greater than 25 watts for each channel.

Automatic volume compensation is incorporated in this amplifier to compensate for variations in the average volume levels of different records and makes possible a volume control setting for normal records without danger of "blasting" or high volume due to exceptionally loud records.

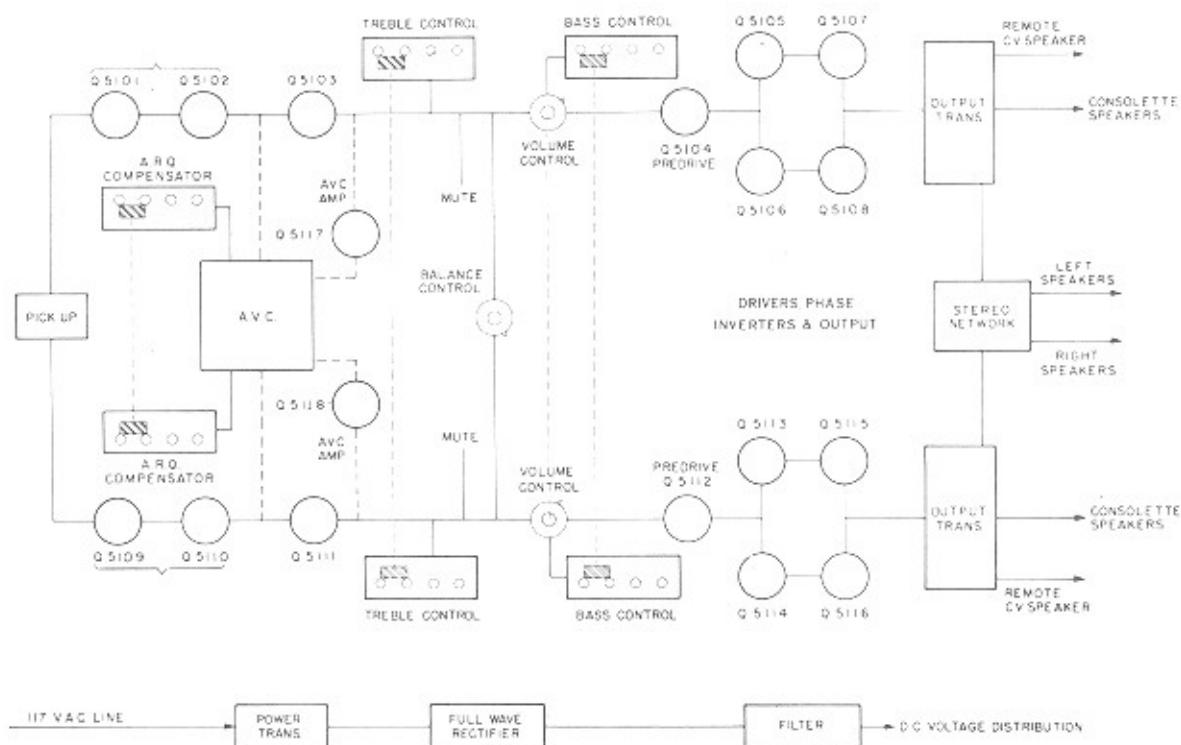
The output of the AVC amplifier transistors Q5117 and Q5118 is rectified by the back-to-back selenium rectifier (CR5105) the output of which is applied as a varying DC bias to two

pairs of matched selenium diodes (CR5103) and (CR5104). Varying the DC bias on these diodes inversely varies the AC reactance and consequently controls the signal level at the bases of voltage amplifier transistors Q5103 and Q5111. The back-to-back selenium rectifier CR5105 also permits squelch voltage to be applied when a record is not being played.

A mute relay (K5101) located in the amplifier is energized through the trip switch and allied circuits in the phonograph. It serves to mute the amplifier by grounding the signal circuits to control the amplifier squelch operation and initiate transfer of a record from playing position.

An Automatic Record Quality Compensator switch (S5103A and S5103B) controls attenuation in the AVC circuit. Its use permits full range operation of the amplifier, but automatically reduces record surface noise when music is at low level.

The volume control adjusts the level of sound from the Select-O-Matic speakers and the remote speakers. It is located on the amplifier so it is accessible from the back of the cabinet. A Powered Remote Volume Control, Type PRVC3, may be used by installation of a motor on the amplifier volume control. The motor is remotely controlled to increase or decrease the phonograph volume.

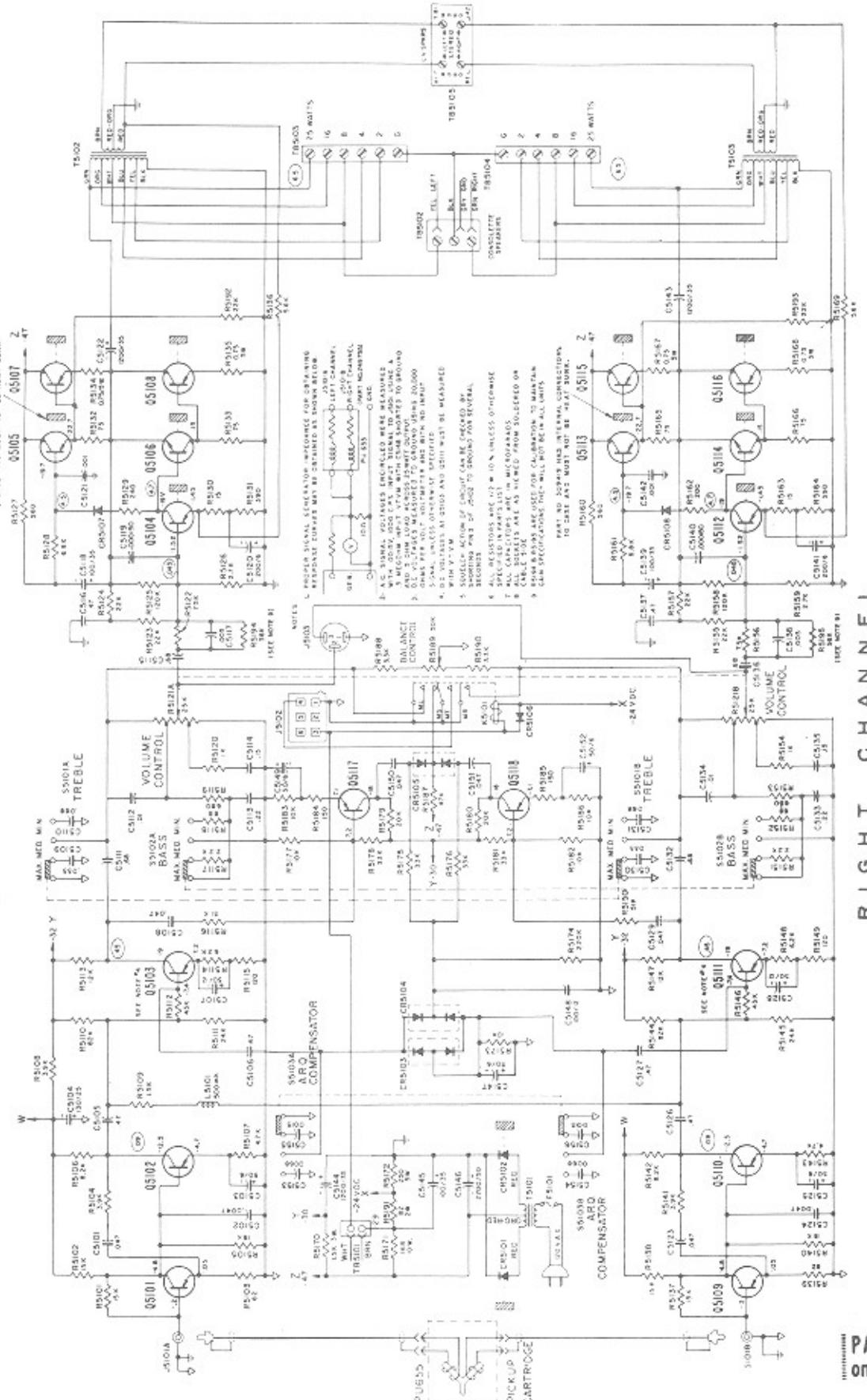


Amplifier Block Diagram.

TRANSISTORIZED STEREO AMPLIFIER, Type TSA4

DRAWING NO. 306752

EFFECT CHANNEL

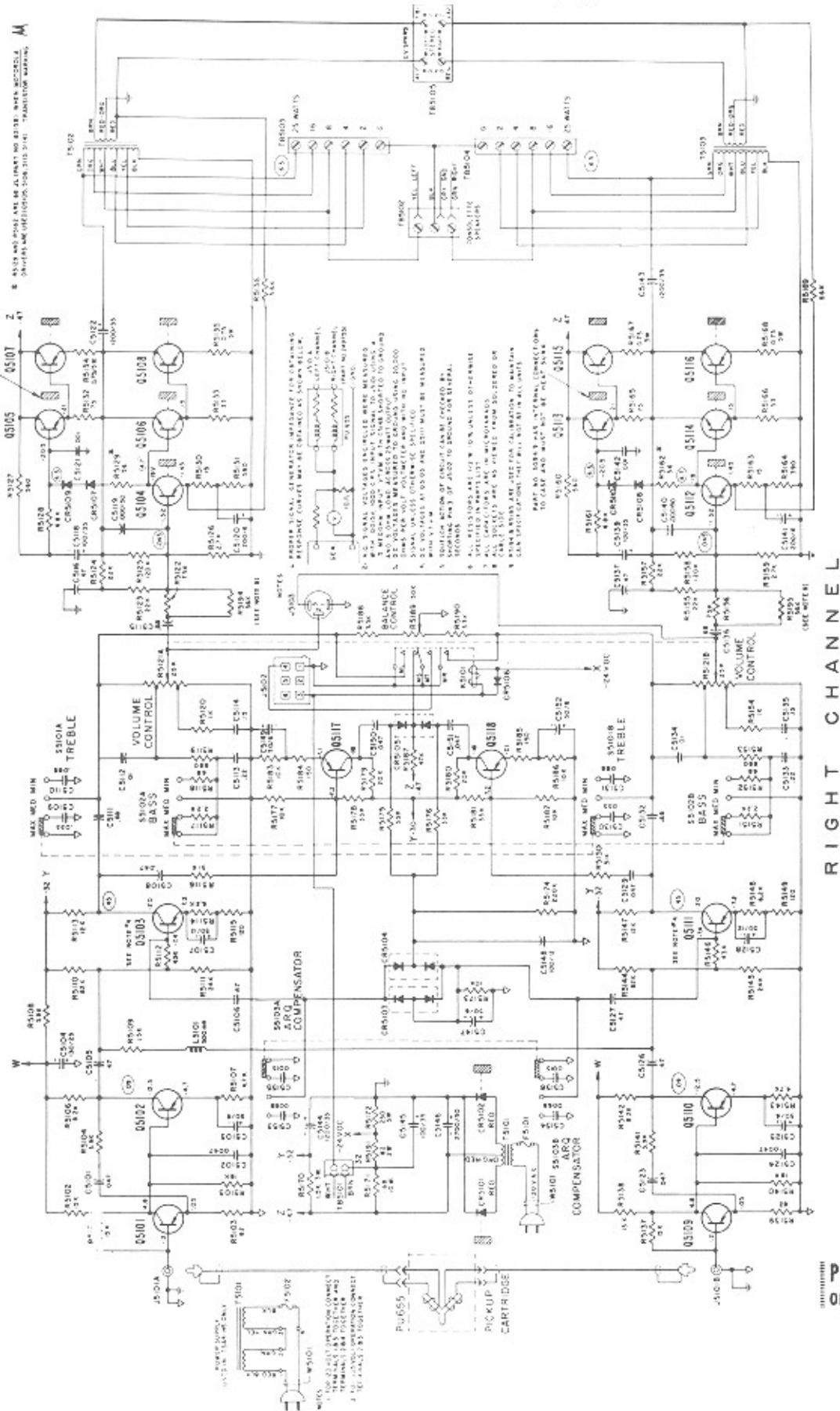


PARTS LIST
on Reverse Side

DRAWING NO. 306752-12

LEFT CHANNEL

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RIGHT CHANNEL

PARTS LIST
on Reverse Side

TRANSISTORIZED STEREO AMPLIFIER, Type TSA4

Item	Part No.	Description	Item	Part No.	Description	Item	Part No.	Description	Item	Part No.	Description
C5101	86321	0.047 Mfd. 50 V. Mylar	C5152	81696	50 Mfd. 6 V. Lytic	R5108	82626	3900 Ohm $\frac{1}{2}$ W. 5%	R5139	82570	27000 Ohm $\frac{1}{2}$ W. 5%
C5102	86330	0.007 Mfd. 50 V. Mylar	C5153	86332	0.008 Mfd. 50 V. Mylar	R5109	82625	1500 Ohm $\frac{1}{2}$ W. 10%	R5150	87421	560 Ohm $\frac{1}{2}$ W. 10%
C5103	87696	50 Mfd. 5 V. Lytic	C5154	86332	0.008 Mfd. 50 V. Mylar	R5110	82445	82000 Ohm $\frac{1}{2}$ W. 10%	R5161	87630	68000 Ohm $\frac{1}{2}$ W. 5%
C5104	87712	1.30 Mfd. 50 V. Lytic	C5155	86340	0.005 Mfd. 500 V. Ceramic	R5111	82605	75000 Ohm $\frac{1}{2}$ W. 5%	R5152	82685	240 Ohm $\frac{1}{2}$ W. 5%
C5105	86329	0.47 Mfd. 50 V. Mylar	C5156	86240	0.015 Mfd. 500 V. Ceramic	R5112	82618	43000 Ohm $\frac{1}{2}$ W. 5%	R5163	82402	15 Ohm $\frac{1}{2}$ W. 10%
C5106	86329	0.47 Mfd. 50 V. Mylar	C5157	86387	Silicon Rectifier 11-212	R5113	82652	12000 Ohm $\frac{1}{2}$ W. 5%	R5164	82688	390 Ohm $\frac{1}{2}$ W. 5%
C5107	87703	50 Mfd. 12 V. Lytic	C5158	86302	Silicon Rectifier U-212	R5114	82610	6200 Ohm $\frac{1}{2}$ W. 5%	R5165	82406	33 Ohm $\frac{1}{2}$ W. 10%
C5108	86327	0.047 Mfd. 50 V. Mylar	C5159	86330	Dual Selenium Diode	R5115	82713	170 Ohm $\frac{1}{2}$ W. 10%	R5167	87406	33 Ohm $\frac{1}{2}$ W. 10%
C5109	86336	0.033 Mfd. 50 V. Mylar	C5160	86397	Dual Selenium Diode	R5116	82795	51000 Ohm $\frac{1}{2}$ W. 5%	R5168	87431	0.25 Ohm 5 W. 10%
C5110	86351	0.068 Mfd. 50 V. Mylar	C5161	86399	Dual Selenium Diode	R5117	82928	23000 Ohm $\frac{1}{2}$ W. 10%	R5169	87431	0.75 Ohm 5 W. 10%
C5111	86354	0.68 Mfd. 50 V. Mylar	C5162	86305	Dual Selenium Diode	R5118	82410	6k Ohm $\frac{1}{2}$ W. 10%	R5169	82433	5600 Ohm $\frac{1}{2}$ W. 10%
C5112	86313	0.01 Mfd. Ceramic	C85106	829384	Semi-Conductor Rectifier (Silcon)	R5119	82422	450 Ohm $\frac{1}{2}$ W. 10%	R5170	87427	1500 Ohm 3 W. 10%
C5113	86331	0.22 Mfd. 50 V. Mylar	C85107	829384	Semi-Conductor Rectifier (Silcon)	R5120	82424	1000 Ohm $\frac{1}{2}$ W. 10%	R5171	87423	168 Ohm 10 W. 10%
C5114	86303	0.15 Mfd. 50 V. Mylar	C5115	86354	0.68 Mfd. 50 V. Mylar	R5121A	8036318	Volume Control 25000 Ohm	R5172	82646	320 Ohm 5 W. 5%
C5116	86329	0.47 Mfd. 50 V. Mylar	F5401	306306	0.8 Amp. Slo-Blo	R5121B	8036318	Volume Control 25000 Ohm	R5174	82456	10000 Ohm $\frac{1}{2}$ W. 10%
C5117	86254	0.005 Mfd. Ceramic	F5402	306359	0.5 Amp. Slo-Blo	R5122	82631	7500 Ohm $\frac{1}{2}$ W. 5%	R5175	82442	30000 Ohm $\frac{1}{2}$ W. 10%
C5118	87700	100 Mfd. 35 V. Lytic	J5101A	8036306	Input Socket	R5123	82639	22000 Ohm $\frac{1}{2}$ W. 5%	R5176	82442	30000 Ohm $\frac{1}{2}$ W. 10%
C5119	86243	0.000150 Mfd. Ceramic	J5101B	8036306	Input Socket	R5124	82639	22000 Ohm $\frac{1}{2}$ W. 5%	R5177	82436	30000 Ohm $\frac{1}{2}$ W. 10%
C5120	87702	200 Mfd. 5 V. Lytic	J5102	809355	Male Jack	R5125	82899	120000 Ohm $\frac{1}{2}$ W. 5%	R5179	82601	20000 Ohm $\frac{1}{2}$ W. 5%
C5121	86339	0.001 Mfd. Ceramic	J5103	12034	Output Socket	R5126	82610	2700 Ohm $\frac{1}{2}$ W. 5%	R5180	82601	20000 Ohm $\frac{1}{2}$ W. 5%
C5122	87718	1200 Mfd. 35 V. Lytic	J5104	809355	Male Jack	R5127	82421	360 Ohm $\frac{1}{2}$ W. 10%	R5181	82442	30000 Ohm $\frac{1}{2}$ W. 10%
C5123	86327	0.047 Mfd. 50 V. Mylar	K5101	306352	Male Trip Relay	R5128	82630	6800 Ohm $\frac{1}{2}$ W. 5%	R5182	82436	10000 Ohm $\frac{1}{2}$ W. 10%
C5124	86330	0.0011 Mfd. 50 V. Mylar	K5102	306352	Male Trip Relay	R5129	82856	240 Ohm $\frac{1}{2}$ W. 5%	R5183	82436	10000 Ohm $\frac{1}{2}$ W. 10%
C5125	87596	50 Mfd. 5 V. Lytic	L5101	306558	Pot Core Inductor Assem. (500 mH)	R5130	82402	15 Ohm $\frac{1}{2}$ W. 10%	R5184	82414	150 Ohm $\frac{1}{2}$ W. 10%
C5126	86329	0.47 Mfd. 50 V. Mylar	C5126	86329	0.47 Mfd. 50 V. Mylar	R5131	82688	390 Ohm $\frac{1}{2}$ W. 5%	R5185	82414	150 Ohm $\frac{1}{2}$ W. 10%
C5127	86329	0.47 Mfd. 50 V. Mylar	C5127	86329	0.47 Mfd. 50 V. Mylar	R5132	82406	33 Ohm $\frac{1}{2}$ W. 10%	R5185	82436	10000 Ohm $\frac{1}{2}$ W. 10%
C5128	87703	50 Mfd. 12 V. Lytic	Q5101	309413	GC-112A PNP Low Noise Germ. Trans.	R5133	82406	33 Ohm $\frac{1}{2}$ W. 10%	R5185	82444	47000 Ohm $\frac{1}{2}$ W. 10%
C5129	86327	0.047 Mfd. 50 V. Mylar	Q5102	309414	GC-112A PNP Germ. Transistor	R5134	82731	0.75 Ohm 5 W. 10%	R5186	82430	33000 Ohm $\frac{1}{2}$ W. 10%
C5130	86326	0.033 Mfd. 50 V. Mylar	Q5103	309420	GC-30 PNP High Gain Germ. Trans.	R5135	82333	0.15 Ohm 5 W. 10%	R5187	82430	Balance Control 30000 Ohm
C5131	86351	0.068 Mfd. 50 V. Mylar	Q5104	309421	RCA 34513 PNP Germ. Transistor	R5136	82336	5000 Ohm $\frac{1}{2}$ W. 10%	R5188	82434	30000 Ohm $\frac{1}{2}$ W. 10%
C5132	86354	0.68 Mfd. 50 V. Mylar	Q5105	309419	SC-365 PNP Silicon Transistor	R5137	828567	15000 Ohm $\frac{1}{2}$ W. 10%	R5189	82436	47000 Ohm $\frac{1}{2}$ W. 10%
C5133	86331	0.22 Mfd. 50 V. Mylar	Q5106	309418	SC-350 NPN Silicon Transistor	R5138	828567	15000 Ohm $\frac{1}{2}$ W. 10%	R5190	82436	22000 Ohm $\frac{1}{2}$ W. 10%
C5134	86313	0.01 Mfd. Ceramic	Q5107	309412	GC-114 PNP Germ. Power Transistor	R5139	82411	82 Ohm $\frac{1}{2}$ W. 10%	R5193	82440	22000 Ohm $\frac{1}{2}$ W. 10%
C5135	86313	0.15 Mfd. 50 V. Mylar	Q5108	309412	GC-114 PNP Germ. Power Transistor	R5140	82739	18000 Ohm $\frac{1}{2}$ W. 10%	R5194	82794	362000 Ohm $\frac{1}{2}$ W. 5%
C5136	86354	0.68 Mfd. 50 V. Mylar	Q5109	309413	GC-112A PNP Low Noise Germ. Trans.	R5141	82836	39000 Ohm $\frac{1}{2}$ W. 5%	R5195	82795	362000 Ohm $\frac{1}{2}$ W. 5%
C5137	86329	0.47 Mfd. 50 V. Mylar	Q5110	309414	GC-112 PNP Germ. Transistor	R5142	828568	82000 Ohm $\frac{1}{2}$ W. 10%	R5196	82430	82 Ohm 2 W. 10%
C5138	86254	0.005 Mfd. Ceramic	Q5111	309420	GC-380 PNP Germ. Power Transistor	R5143	82832	4700 Ohm $\frac{1}{2}$ W. 10%	R5197	82440	22000 Ohm $\frac{1}{2}$ W. 10%
C5139	87700	100 Mfd. 35 V. Lytic	Q5112	309421	RCA 34513 PNP Germ. Transistor	R5144	82447	82000 Ohm $\frac{1}{2}$ W. 10%	R5198	82000A	8.55s Switch
C5140	86243	0.000150 Mfd. Ceramic	Q5113	309419	SC-365 PNP Silicon Transistor	R5145	82625	24000 Ohm $\frac{1}{2}$ W. 5%	R5199	82000B	2.16 Terminal Board
C5141	87702	200 Mfd. 6 V. Lytic	Q5114	309418	SC-365 PNP Germ. Power Trans.	R5146	82678	43000 Ohm $\frac{1}{2}$ W. 5%	R5200A	82000C	3.16 Terminal Board
C5142	86309	0.001 Mfd. Ceramic	Q5115	309417	SC-114 PNP Germ. Power Trans.	R5147	828962	120000 Ohm $\frac{1}{2}$ W. 5%	R5200B	82000D	3.16 Terminal Board
C5143	87718	1200 Mfd. 35 V. Lytic	Q5116	309414	GC-112 PNP Germ. Power Trans.	R5148	82610	52000 Ohm $\frac{1}{2}$ W. 5%	R5200C	82000D	3.16 Terminal Board
C5144	87718	1200 Mfd. 35 V. Lytic	Q5117	309414	GC-112 PNP Germ. Transistor	R5149	82413	120 Ohm $\frac{1}{2}$ W. 10%	R5201A	82612	Power Transformer for 60 cycles
C5145	87700	100 Mfd. 35 V. Lytic	Q5118	309414	GC-112 PNP Germ. Transistor	R5150	82796	34000 Ohm $\frac{1}{2}$ W. 5%	R5201B	82612	Power Transformer for 60 cycles
C5146	87721	2700 Mfd. 50 V. Lytic	Q5119	309414	GC-112 PNP Germ. Transistor	R5151	82478	22000 Ohm $\frac{1}{2}$ W. 10%	R5202	82612	Output Transformer
C5147	87718	1200 Mfd. 35 V. Lytic	Q5120	309414	GC-112 PNP Germ. Transistor	R5152	82410	68 Ohm $\frac{1}{2}$ W. 10%	R5203	82612	Output Transformer
C5148	87721	2700 Mfd. 50 V. Lytic	Q5121	309414	GC-112 PNP Germ. Transistor	R5153	82422	680 Ohm $\frac{1}{2}$ W. 10%	R5204	82612	Output Transformer
C5149	87724	100 Mfd. 12 V. Lytic	Q5122	309414	GC-112 PNP Germ. Transistor	R5154	82744	10000 Ohm $\frac{1}{2}$ W. 10%	R5205	82612	Output Transformer
C5150	87536	50 Mfd. 6 V. Lytic	Q5123	309414	GC-112 PNP Germ. Transistor	R5155	82636	22000 Ohm $\frac{1}{2}$ W. 5%	R5206	82612	Output Transformer
C5151	86327	0.047 Mfd. 50 V. Mylar	Q5124	309414	GC-112 PNP Germ. Transistor	R5156	82631	7600 Ohm $\frac{1}{2}$ W. 5%	R5207	82612	Output Transformer
C5152	86327	0.047 Mfd. 50 V. Mylar	Q5125	309414	GC-112 PNP Germ. Transistor	R5157	82639	7600 Ohm $\frac{1}{2}$ W. 5%	R5208	82612	Output Transformer
C5153	86327	0.047 Mfd. 50 V. Mylar	Q5126	309414	GC-112 PNP Germ. Transistor	R5158	82899	130000 Ohm $\frac{1}{2}$ W. 5%	R5209	82612	Output Transformer

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Description					
Part No.	Item	Part No.	Item	Part No.	Description
R5108	C5152	87695	50 Mfd. 6 V. Lytic	R5108	82676 3900 Ohm ½ W. 5%
R5109	C5153	86332 0.0038 Mfd. 50 V. Mylar	R5109	83426 1500 Ohm ½ W. 10%	
R5110	C5154	86332 0.0038 Mfd. 50 V. Mylar	R5110	83447 23000 Ohm ½ W. 10%	
R5111	C5155	86240 0.0015 Mfd. 500 V. Ceramic	R5111	82856 24000 Ohm ½ W. 5%	
R5112	C5156	86240 0.0015 Mfd. 500 V. Ceramic	R5112	808528 43000 Ohm ½ W. 5%	
R5113	C85100	309389 Silicon Rectifier	R5113	308562 120000 Ohm ½ W. 5%	
R5114	C85103	309385 Silicon Rectifier	R5114	82610 6200 Ohm ½ W. 5%	
R5115	C85103	309385 Dual Selenium Diode	R5115	83413 1200 Ohm ½ W. 10%	
R5116	C85104	309397 Dual Selenium Diode	R5116	82196 510000 Ohm ½ W. 5%	
R5117	C85105	309399 Dual Selenium Diode	R5117	82428 22000 Ohm ½ W. 10%	
R5118	C85106	309384 Sem-Conductor Rectifier (Si) cont	R5118	83241 53000 Ohm ½ W. 10%	
R5119	C85107	309313 .01 Mfd. Ceramic	R5119	82422 58000 Ohm ½ W. 10%	
R5120	C85108	309313 .22 Mfd. 50 V. Mylar	R5120	82424 100000 Ohm ½ W. 10%	
R5121A	C85109	309473 Silicon Stabilistor	R5121A	106318 Volume Control, 25000 Ohm	
R5121B	C85110	309473	R5121B	82442 33000 Ohm ½ W. 10%	
R5122	F5101	306316 0.8 Amp. SiO-Blo	R5122	82631 75000 Ohm ½ W. 5%	
R5123	F5102	306359 0.5 Amp. SiO-Blo	R5123	878539 230000 Ohm ½ W. 5%	
R5124	J5010A	306319 MC. Ceramic	R5124	826339 230000 Ohm ½ W. 5%	
R5125	J5010B	306306 Input Socket	R5125	82899 1200000 Ohm ½ W. 5%	
R5126	J5102	306355 Mate Jack	R5126	82670 27000 Ohm ½ W. 5%	
R5127	J5103	12034 Output Socket	R5127	82421 56000 Ohm ½ W. 10%	
R5128	M5101	306352 Mate 1A Relay	R5128	82630 64000 Ohm ½ W. 5%	
R5129	M5102	306352 Mate 1A Relay	R5129	(See Notes 1 & 2)	
R5130	L5101	306558 Pat Con Inductor Assen(500 mH)	R5130	82402 150000 Ohm ½ W. 10%	
R5131	L5102	306558 Pat Con Inductor Assen(500 mH)	R5131	82688 350000 Ohm ½ W. 5%	
R5132	Q5101	309413 GC-111A PNP Low Noise Germ. Transistor	R5132	82649 750000 Ohm ½ W. 5%	
R5133	Q5102	309414 GC-112 PNP Germ. Transistor	R5133	82405 330000 Ohm ½ W. 10%	
R5134	Q5103	309420 GC-380 PNP High Gain Germ. Transistor	R5134	81231 0.75 Ohm 5 W. 10%	
R5135	Q5104	309421 RCA 3453 PNP Germ. Transistor	R5135	81231 0.75 Ohm 5 W. 10%	
R5136	Q5105	309414 SC-305 PNP Silicon Transistor	R5136	82433 500000 Ohm ½ W. 10%	
R5137	Q5106	309414 SC-305 XPN Silicon Transistor	R5137	808647 150000 Ohm ½ W. 10%	
R5138	Q5107	309412 GC-114 PNP Germ. Power Transistor	R5138	808667 150000 Ohm ½ W. 10%	
R5139	Q5108	309412 GC-114 PNP Germ. Power Transistor	R5139	82411 820000 Ohm ½ W. 10%	
R5140	Q5109	309412 GC-114 PNP Germ. Power Transistor	R5140	82339 180000 Ohm ½ W. 10%	
R5141	Q5110	309414 GC-112A PNP Low Noise Germ. Transistor	R5141	82636 350000 Ohm ½ W. 5%	
R5142	Q5111	309414 SC-351 NPN Silicon Transistor	R5142	808668 600000 Ohm ½ W. 10%	
R5143	Q5112	309412 GC-380 PNP High Gain Germ. Transistor	R5143	82432 420000 Ohm ½ W. 10%	
R5144	Q5113	309419 SC-365 PNP Silicon Transistor	R5144	82447 600000 Ohm ½ W. 10%	
R5145	Q5114	309414 GC-114 PNP Germ. Transistor	R5145	82095 240000 Ohm ½ W. 5%	
R5146	Q5115	309414 SC-350 NPN Silicon Transistor	R5146	82678 420000 Ohm ½ W. 10%	
R5147	Q5116	309412 GC-114 PNP Germ. Power Transistor	R5147	808662 1200000 Ohm ½ W. 5%	
R5148	Q5117	309412 GC-112 PNP Germ. Power Transistor	R5148	82413 1200000 Ohm ½ W. 10%	
R5149	Q5118	309414 GC-112 PNP Germ. Transistor	R5149	82196 5100000 Ohm ½ W. 5%	
R5150	Q5119	309414 GC-112 PNP Germ. Transistor	R5150	82196 5100000 Ohm ½ W. 5%	
R5151	Q5120	309414 GC-112 PNP Germ. Transistor	R5151	82428 2000000 Ohm ½ W. 5%	
R5152	Q5121	309414 GC-112 PNP Germ. Transistor	R5152	82410 5600000 Ohm ½ W. 10%	
R5153	Q5122	309412 GC-114 PNP Germ. Transistor	R5153	82422 6800000 Ohm ½ W. 10%	
R5154	Q5123	309412 GC-114 PNP Germ. Transistor	R5154	82424 1000000 Ohm ½ W. 10%	
R5155	Q5124	309412 GC-112 PNP Germ. Transistor	R5155	82539 2000000 Ohm ½ W. 5%	
R5156	Q5125	309412 GC-112 PNP Germ. Transistor	R5156	82519 7500000 Ohm ½ W. 5%	
R5157	Q5126	309414 GC-112 PNP Germ. Transistor	R5157	82639 2000000 Ohm ½ W. 5%	
R5158	Q5127	309414 GC-112 PNP Germ. Transistor	R5158	82859 1200000 Ohm ½ W. 5%	
R5159	Q5128	309414 GC-112 PNP Germ. Transistor	R5159	82630 2700000 Ohm ½ W. 5%	

4116A

Issue 1

THE SEEBURG SALES CORPORATION, CHICAGO, ILLINOIS 60622